

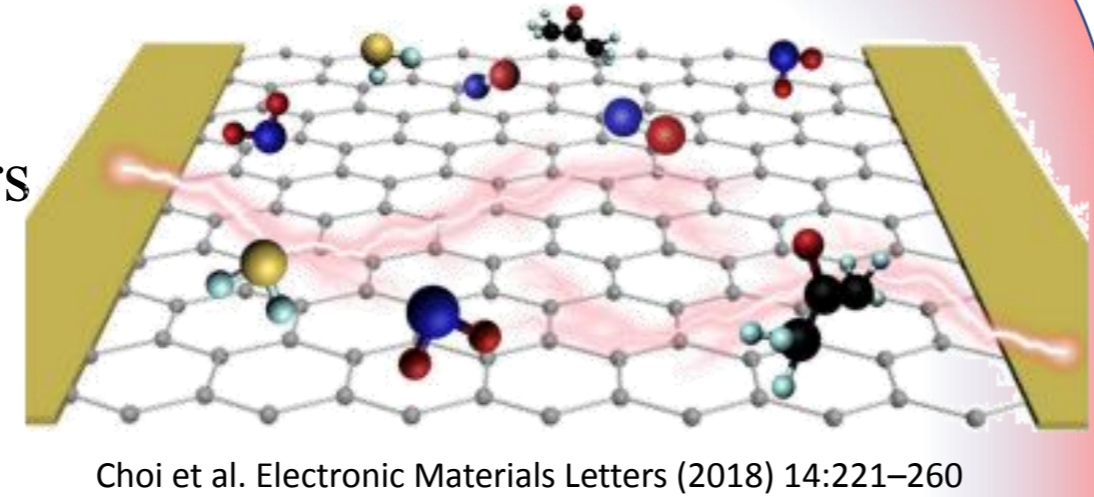
Theoretical investigation of gas molecule adsorption on WS monochalcogenide

Dhanshree Pandey, Aparna Chakrabarti

Motivation

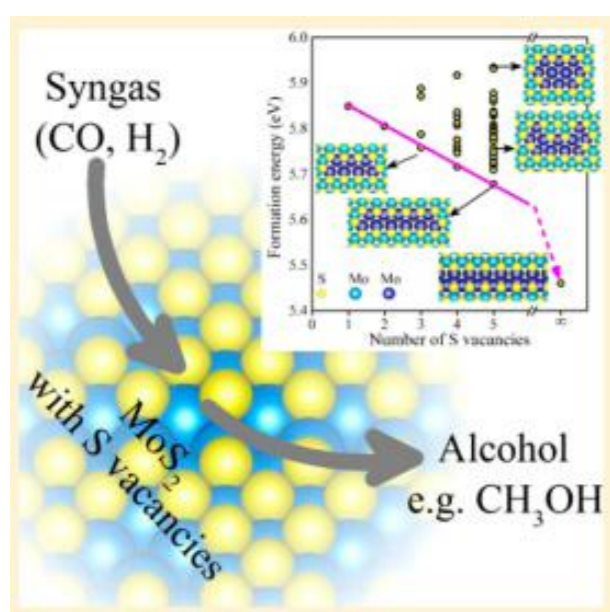
Why need Gas Sensors:

- ✓ Quickly identify toxic gases and organic vapours
- ✓ For environmental and human safety
- ✓ For the emission control
- ✓ In industry sector, etc.



Why 2 Dimensional nanomaterials

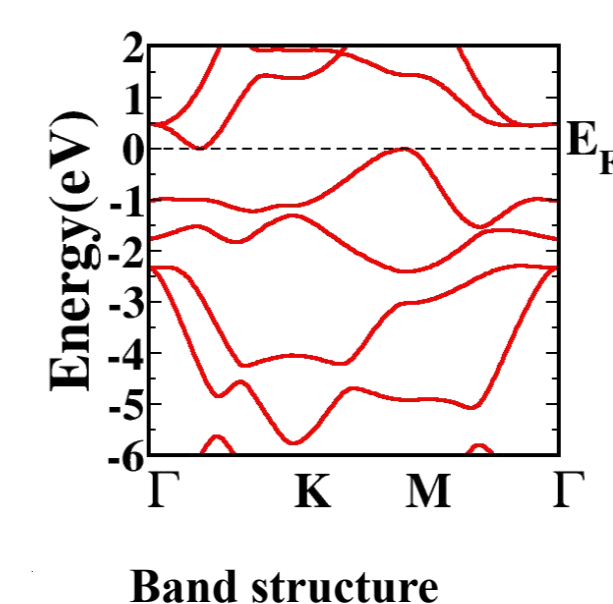
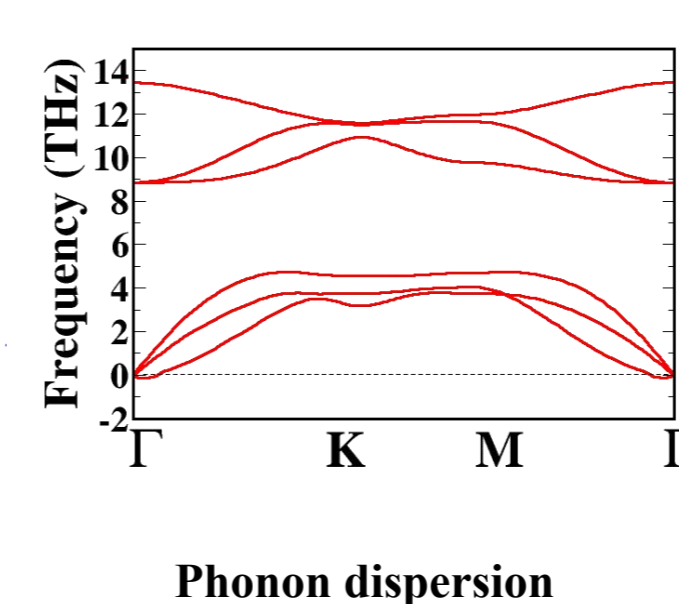
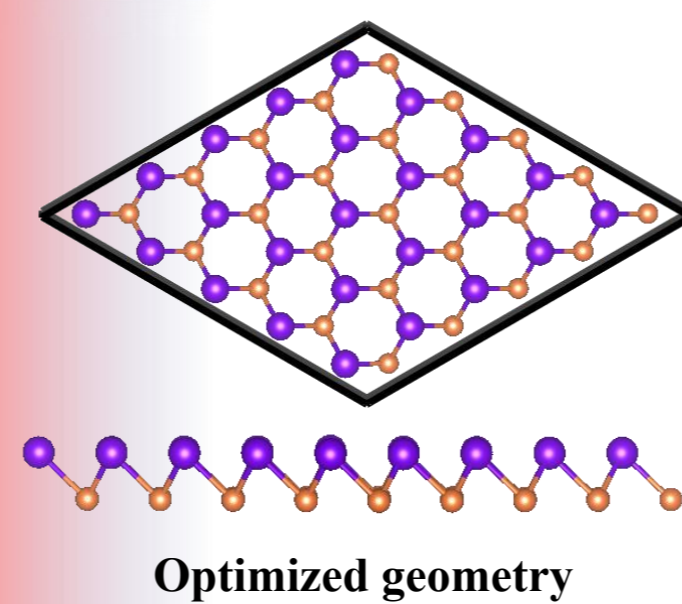
- 2D layered nanomaterials possess **large surface area** and **high surface-to-volume ratio**
- The interaction between adsorbates and pristine graphene is generally quite weak: **pristine graphene is chemically stable at ambient environments.**
- For the transition metal dichalcogenides (TMDs), **the layers are stable against the interaction between environmental species with the absence of dangling bonds**



3.3. MoS₂ with Sulfur Vacancies for Catalytic Application. The existence of the sulfur-vacancy rows and the possibility to control their directions³⁸ suggest a possibility of using them for catalytic applications since, as discussed in the Introduction section, sulfur vacancies will provide great conditions for catalytic activity: Mo atoms and their d-electrons are exposed to adsorbates. It is important to note that the variation of formation
Kim et al. Chemosensors 5, 15 (2017)

Single-Layer MoS₂ with Sulfur Vacancies: Structure and Catalytic Application, Li et al., J. Phys. Chem. C, 118, 5346 (2014)

Prediction of WS monochalcogenide



Systems	E _B /atom (eV/atom)	a(Å)	Buckling height, Δ (Å)	Charge Transfer, ΔQ (e)
WS-buckled	-5.84	2.98	1.62	0.55

- Variable coordination number (due to presence of d-orbitals) of TMs allows their reactivity.
- WS monochalcogenide has the W atoms on the surface and hence has active site for gas adsorption.

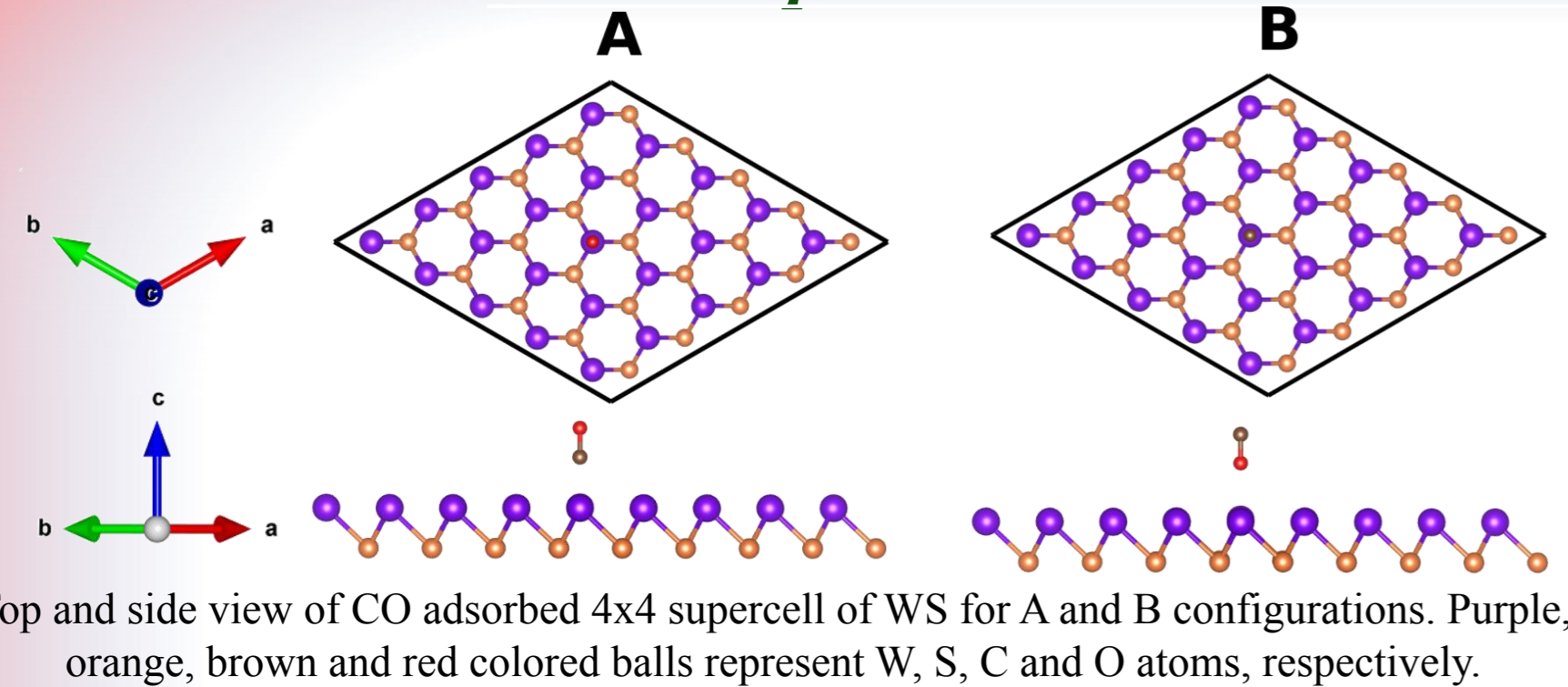
Methodology

- Density Functional Theory (DFT) based electronic structure calculations have been performed using Vienna Ab-initio Simulation Package (VASP).
- Exchange correlation functional: Generalized gradient approximation (GGA) given by Perdew, Burke, and Ernzerhof (PBE)
- Plane wave cutoff- 500 eV
- k points- 7x7x1
- Vacuum length- 16 Å
- Energy convergence criterion: 10⁻⁶ eV
- van der Waals correction through DFT-D3
- Adsorption energy has been calculated to find the stable configuration

$$\text{Adsorption Energy, } E_{\text{ads}} = E_{2\text{D}+\text{gas}} - E_{2\text{D}} - E_{\text{gas}}$$

Results and Discussion

CO adsorption on WS monochalcogenide

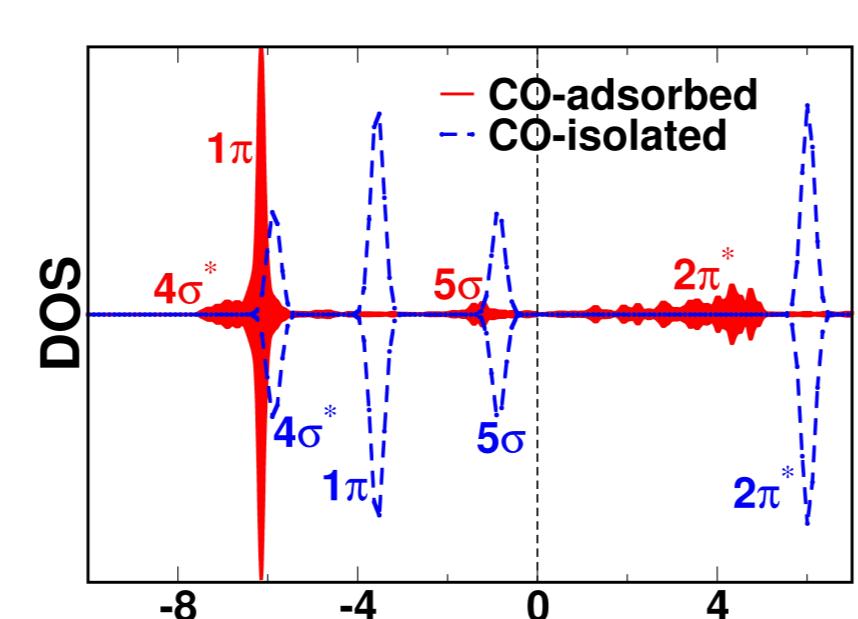
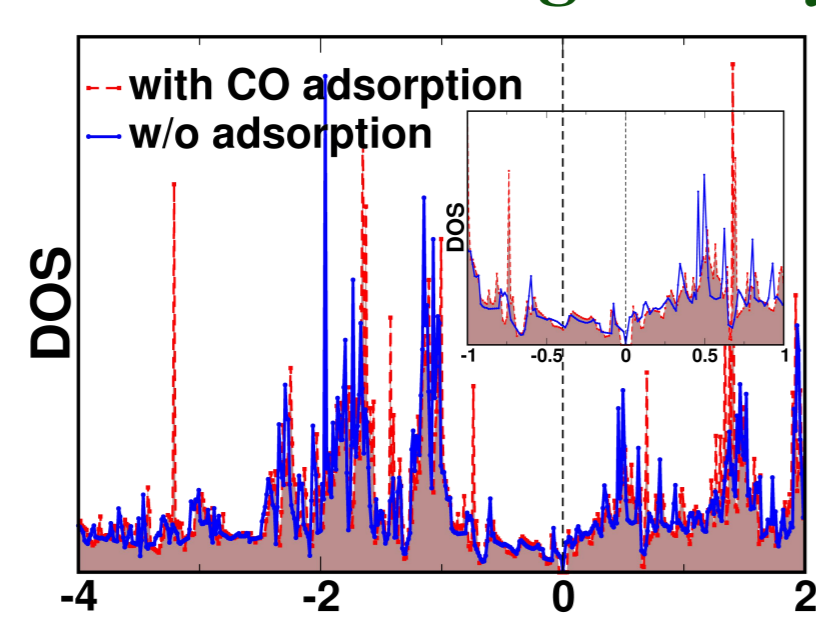
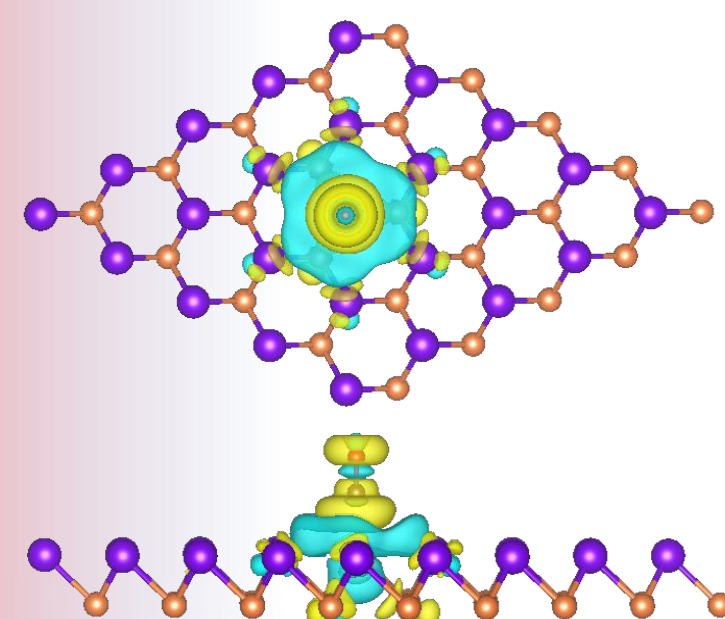


(a) HOMO and (b) LUMO of CO molecule (the C atom is black and the O atom is red)*
*Leenaerts et al. Phys. Rev. B 77, 125416 (2008)

- Configuration A is preferred for the CO adsorption.
- LUMO of CO molecule is primarily located on the less electronegative C atom.
- Large charge transfer takes place when C atom is facing the sheet.

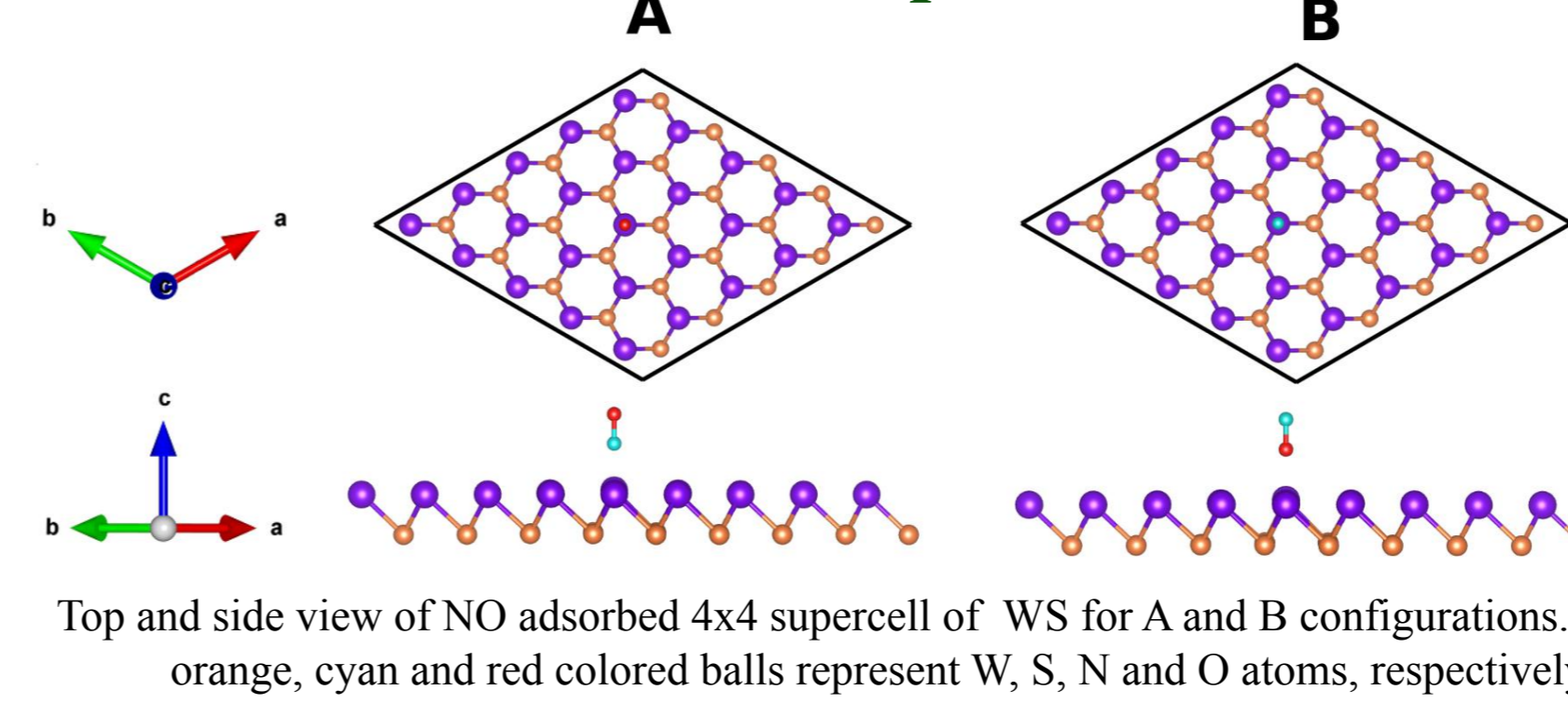
Configuration	E _{ads} (eV)	Δq (e)	C-O (Å)	D(W-C or W-O) (Å)
A	-2.44	-0.40	1.17	2.03
B	-0.32	-0.14	1.16	2.27

Electronic structure and Charge Analysis



- Electron accumulation around the CO molecule with the depletion around the WS sheet.
- WS shows a transition to a semiconducting character upon CO adsorption.

NO adsorption on WS monochalcogenide

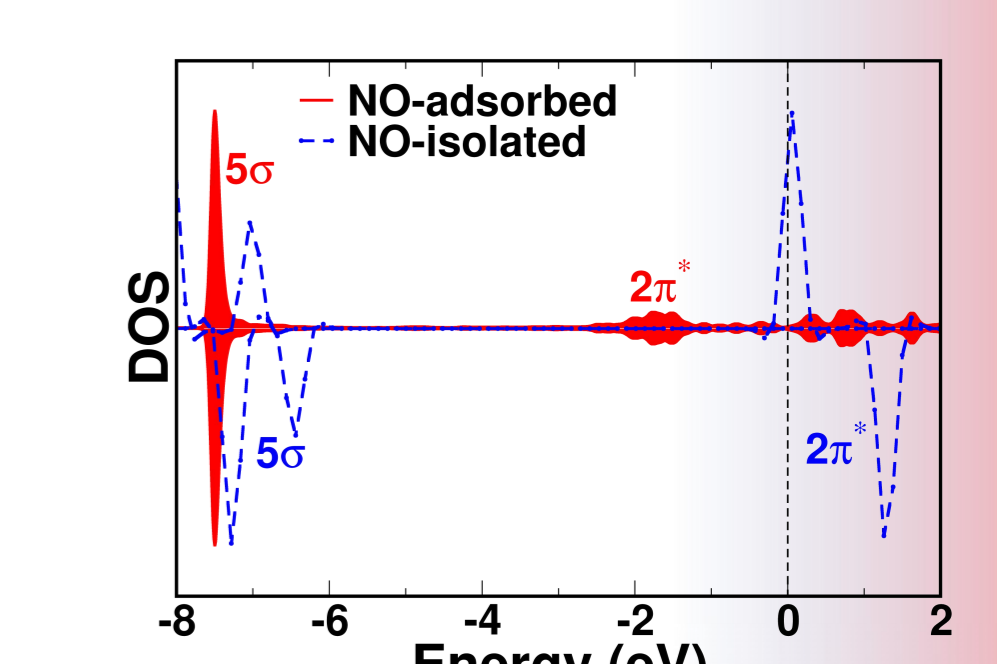
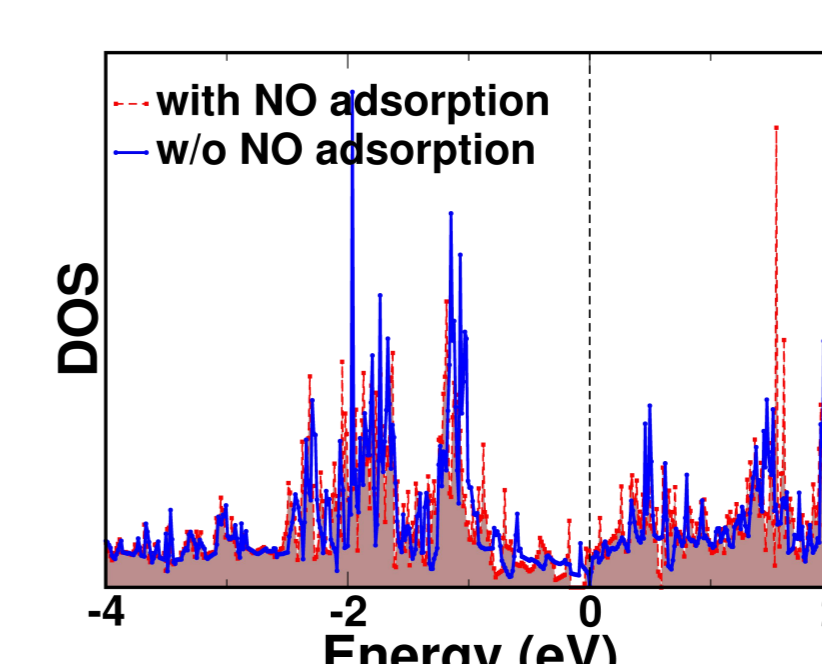
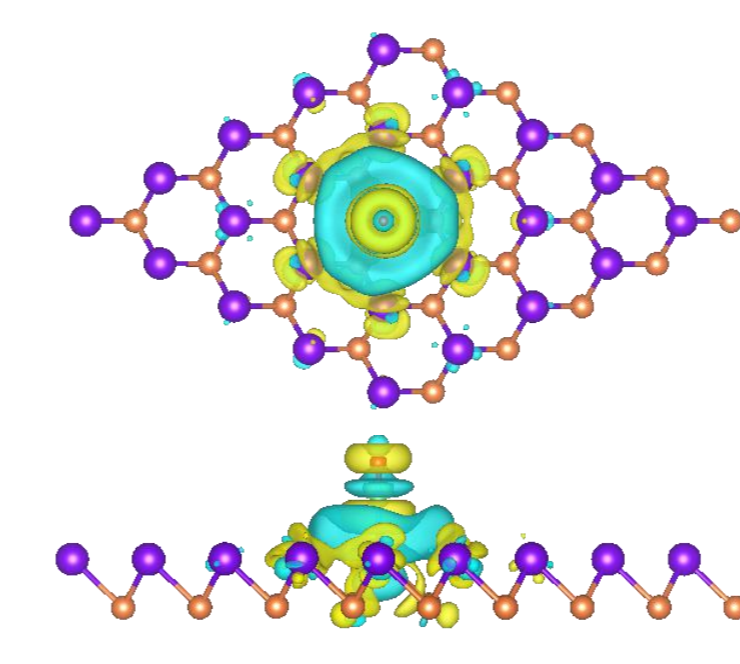


(a) 5σ orbital and (b) HOMO/LUMO of NO (the N atom is blue and the O atom is red).
*Leenaerts et al. Phys. Rev. B 77, 125416 (2008)

- Configuration A is preferred for the NO adsorption, similar to CO adsorption.
- HOMO/LUMO of NO molecule is primarily located on N atom.

Configuration	E _{ads} (eV)	Δq (e)	N-O (Å)	D(W-N or W-O) (Å)
A	-2.80	-0.49	1.19	1.89
B	-0.97	-0.34	1.19	2.02

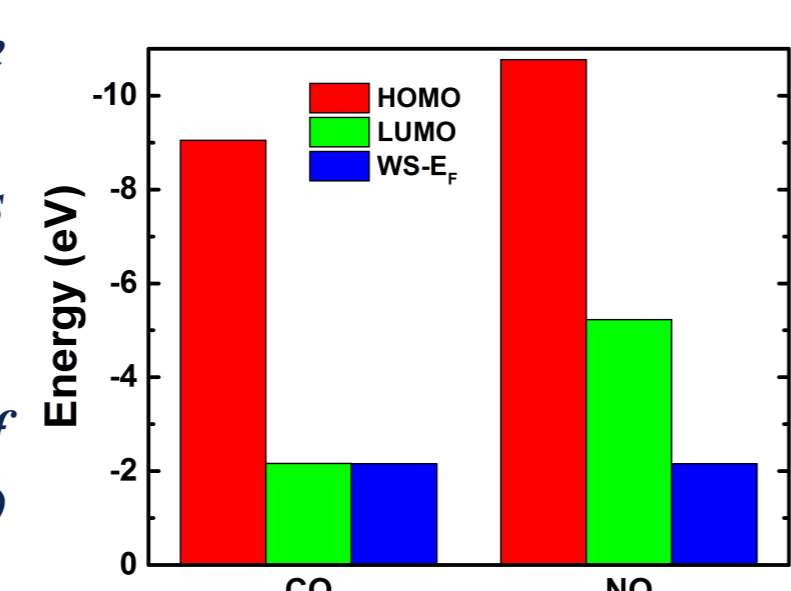
Electronic structure and Charge Analysis



- Electron accumulation around the NO molecule with the depletion around the WS sheet.
- Consistent with the direction of the charge transfer from 2D sheet to the NO molecule.
- Upon NO adsorption, appreciable change in the electronic structure is observed.

Charge Transfer Theory

- A charge transfer depend on the relative positions of the highest occupied molecular orbital (HOMO) and the lowest un-occupied molecular orbital (LUMO) of the gas molecules.
- LUMO of CO molecule is located at -2.162 eV and E_F of WS at -2.157 eV, hence charge transfer from WS to CO molecule
- Similar argument holds good for the charge transfer from WS to NO molecule.
- This analysis is consistent with the Bader charge analysis and DCD.



Comparison of E_{ads} (in eV) for CO and NO gas adsorption on different 2D nanostructures from literature

System	CO	NO
Graphene ^{1,2}	-0.01 (-0.12)	-0.03 (-0.30)
Silicene ³	-0.18	-0.35
Phosphorene ⁴	-0.31	-0.31
Borophene ⁵	-1.38	-1.79
MoS ₂ ⁶	-0.44	-0.55
WS ₂ ⁷	-0.13	-0.22
WS	-2.44	-2.80

Summary and Conclusion

- Adsorption of CO and NO gases on 2D surfaces of pristine buckled WS monochalcogenide has been studied.
- E_{ads}, Bader charge analysis and the difference charge density analysis reveal that, both, CO and NO molecule prefer the adsorption on the 2D sheet with C or N, respectively, pointing towards the sheet.
- Charge transfer theory has been discussed to study the direction of charge transfer from the sheet to molecule
- Significant changes in the electronic states have been observed for both the cases with semimetallic to semiconductor transition in case of adsorption of CO gas molecule on the WS monolayer
- CO and NO molecule adsorbed systems have high value of E_{ads} which suggest their applicability as a potential candidate for gas sensor.

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